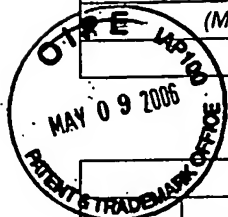


**SUPPLEMENTAL INFORMATION
DISCLOSURE
STATEMENT BY APPLICANT**

(Multiple sheets used when necessary)

SHEET 1 OF 1

Application No.	10/771,176
Filing Date	February 3, 2004
First Named Inventor	Chih-Hsing Cheng
Art Unit	1731
Examiner	Queenie S. Dehghan
Attorney Docket No.	SITECH.017CPICP



FOREIGN PATENT DOCUMENTS

Examiner Initials	Cite No.	Foreign Patent Document	Publication Date	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear	T ¹
	1	EP 0 852 164 A1	05/10/1995	Alcatel Cable Interface		
QSD	2	EP 0 131 057 B1	11/04/1987	Toki et al.		
QSD	3	GB 2 170 799 A	08/13/1996	Seiko Epson Corporation		

Examiner Initials	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)					
QSD	4	Brinker et al., <i>Sol-Gel Science, The Physics and Chemistry of Sol-Gel Processing</i> , Academic Press (1990), pp. 483-498.				
QSD	5	Heaney, A.D., et al., <i>Solgel-derived Photosensitive Germanosilicate Glass Monoliths</i> , <i>Optics Letters</i> , Vol. 25, No. 24 (December 15, 2000), pp. 1765-1767.				
QSD	6	Kawaguchi et al., <i>Structural Changes of Monolithic Silica Gel During the Gel-to-Glass Transition</i> , <i>J. Non-Crystalline Solids</i> , Vol. 82 (1986), pp. 50-56.				
QSD	7	Kirkbir et al., <i>Parametric Study of Strength of Silica Gels</i> , <i>J. Non-Crystalline Solids</i> , Vol. 178 (1994), pp. 284-292.				
QSD	8	Murata, et al., <i>Drying and Sintering of Large SiO₂ Monoliths</i> , <i>SPIE</i> , Vol. 2288, Sol-Gel Optics III (1994) pp. 709-716.				

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Examiner Signature	/Queenie Dehghan/	Date Considered	7/17/06
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			

T¹ - Place a check mark in this area when an English language Translation is attached.